# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



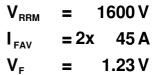
### **DSIK45-16AR**

Standard	Rectifier
----------	-----------

**Common Cathode** 

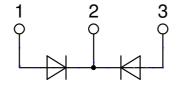
Part number

**DSIK45-16AR** 









### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

### **Applications:**

• Diode for main rectification

### Package: ISOPLUS247

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

#### Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact the sales office, which is responsible for you. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact the sales office, which is responsible for you. Should you intend to use the product in aviation, in health or live endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

20130215a

## LIXYS

## DSIK45-16AR

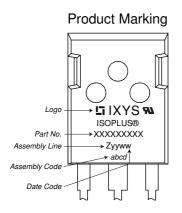
Rectifier					Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V <sub>RSM</sub>	max. non-repetitive reverse bloc	king voltage	$T_{VJ} = 25^{\circ}C$			1700	V	
V <sub>RRM</sub>	max. repetitive reverse blocking	voltage	$T_{VJ} = 25^{\circ}C$			1600	V	
I <sub>R</sub>	reverse current	$V_{R} = 1600 V$	$T_{VJ} = 25^{\circ}C$			40	μA	
		$V_{R} = 1600 V$	$T_{vJ} = 150^{\circ}C$			1.5	mA	
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 45 A	$T_{VJ} = 25^{\circ}C$			1.26	V	
		I <sub>F</sub> = 90 A				1.57	V	
		$I_F = 45 \text{ A}$	$T_{vJ} = 150 ^{\circ}C$			1.23	V	
		$I_{F} = 90 \text{ A}$				1.66	V	
FAV	average forward current	T <sub>c</sub> = 100°C	T <sub>vJ</sub> = 175°C			45	A	
		sine 180°						
V <sub>F0</sub>	threshold voltage $T_{vJ} =$					0.81	V	
r <sub>F</sub>	slope resistance } for power	loss calculation only				9.1	mΩ	
<b>R</b> <sub>thJC</sub>	thermal resistance junction to ca	ase				0.9	K/W	
R <sub>thCH</sub>	thermal resistance case to heats	sink			0.25		K/W	
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			165	W	
I <sub>FSM</sub>	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			480	A	
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			520	Α	
		t = 10 ms; (50 Hz), sine	$T_{vJ} = 150^{\circ}C$			410	A	
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			440	Α	
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			1.15	kA²s	
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			1.13	kA²s	
		t = 10 ms; (50 Hz), sine	$T_{vJ} = 150^{\circ}C$			840	A <sup>2</sup> s	
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			805	A²s	
CJ	junction capacitance	V <sub>B</sub> = 400 V; f = 1 MHz	$T_{vJ} = 25^{\circ}C$		18		pF	

20130215a

## **I**IXYS

## DSIK45-16AR

Package ISOPLUS247				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal 10				70	Α
T <sub>vj</sub>	virtual junction temperature			-40		175	°C
T <sub>op</sub>	operation temperature			-40		150	°C
T <sub>stg</sub>	storage temperature			-40		150	°C
Weight					6		g
F <sub>c</sub>	mounting force with clip			20		120	Ν
d <sub>Spp/App</sub>	creepage distance on surface   strikin	a distance through air	terminal to terminal	2.7			mm
<b>d</b> <sub>Spb/Apb</sub>		ig distance through an	terminal to backside	4.1			mm
V	isolation voltage	t = 1 second		3600			V
	t = 1 minute 50/60 Hz, RMS; liso∟ ≤ 1 mA		50/60 Hz, KMS; liso∟ ≤ 1 mA	3000			V



0	rdering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
S	standard	DSIK45-16AR	DSIK45-16AR	Tube	30	496022

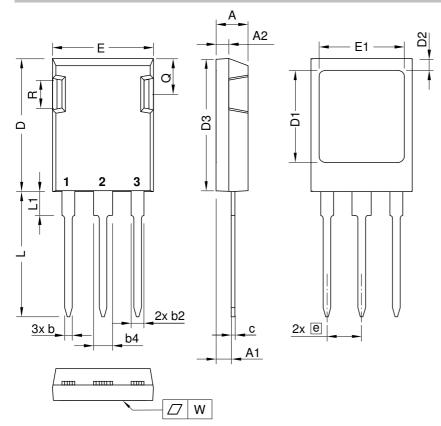
Equiv	alent Circuits for	Simulation	* on die level	T <sub>vj</sub> = 175 °C
	$-R_{o}-$	Rectifier		
V <sub>0 max</sub>	threshold voltage	0.81		V
$\mathbf{R}_{0 \text{ max}}$	slope resistance *	6.5		mΩ

IXYS reserves the right to change limits, conditions and dimensions.

20130215a

# LIXYS

### Outlines ISOPLUS247

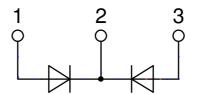


Dim.	Millir	neter	Inc	hes
Dim.	min	max	min	max
Α	4.83	5.21	0.190	0.205
A1	2.29	2.54	0.090	0.100
A2	1.91	2.16	0.075	0.085
b	1.14	1.40	0.045	0.055
b2	1.91	2.20	0.075	0.087
b4	2.92	3.24	0.115	0.128
С	0.61	0.83	0.024	0.033
D	20.80	21.34	0.819	0.840
D1	15.75	16.26	0.620	0.640
D2	1.65	2.15	0.065	0.085
D3	20.30	20.70	0.799	0.815
Е	15.75	16.13	0.620	0.635
E1	13.21	13.72	0.520	0.540
е	5.45	BSC	0.215 BSC	
L	19.81	20.60	0.780	0.811
L1	3.81	4.38	0.150	0.172
Q	5.59	6.20	0.220	0.244
R	4.25	5.50	0.167	0.217
W	-	0.10	-	0.004

Die konvexe Form des Substrates ist typ. < 0.04 mm über der Kunststoffoberfläche der Bauteilunterseite The convex bow of substrate is typ. < 0.04 mm over plastic

surface level of device bottom side Die Gehäuseabmessungen entsprechen dem Typ TO-247 AD

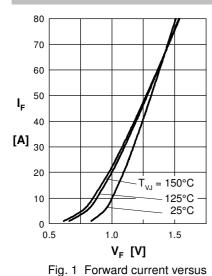
gemäß JEDEC außer Schraubloch und L<sub>max</sub>. This drawing will meet all dimensions requirement of JEDEC outline TO-247 AD except screw hole and except L<sub>max</sub>.



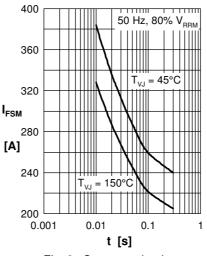
IXYS reserves the right to change limits, conditions and dimensions.

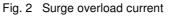
### DSIK45-16AR

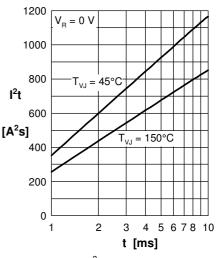
### Rectifier

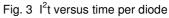


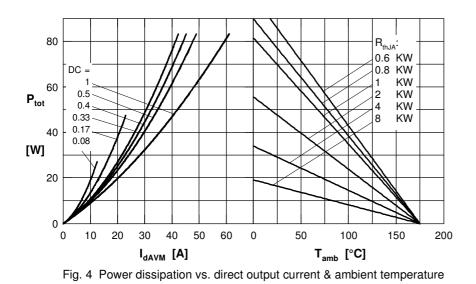
voltage drop per diode











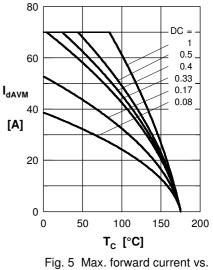
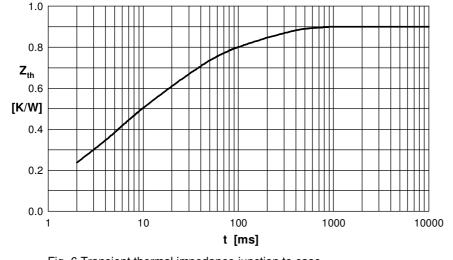
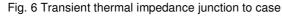


Fig. 5 Max. forward current vs case temperature



i	Ri	ti
1	0.0607	0.0004
2	0.123	0.00256
3	0.2305	0.045
4	0.323	0.0242
5	0.1628	0.18



IXYS reserves the right to change limits, conditions and dimensions.